Zibo Seno Electronic Engineering Co., Ltd.

淄博圣诺

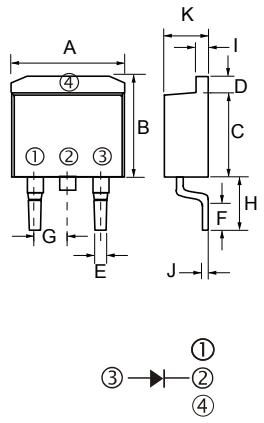
MBR640G – MBR6200G

6.0 A SCHOTTKY BARRIER DIODE

Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

TO-263AC/ D^2PAK



TO-263AC/ D^2PAK		
DIM.	MIN.	MAX.
A	9.80	10.20
B	9.60	10.60
C	8.50	9.20
D	----	1.67
E	0.51	1.01
F	2.10	2.50
G	2.44	2.64
H	4.40	4.70
I	1.10	1.40
J	0.30	0.64
K	4.40	4.80
All Dimensions in millimeter		

Mechanical Data

- Case: TO-263AC(D^2PAK), Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 640G	MBR 645G	MBR 650G	MBR 660G	MBR 680G	MBR 6100G	MBR 6150G	MBR 6200G	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	40	45	50	60	80	100	150	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	28	31	35	42	56	70	105	140	V
Average Rectified Output Current @T_L = 100°C (Note 1)	I_O	6.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	100								A
Forward Voltage @I_F = 6A	V_{FM}	0.70		0.80		0.85		0.92		V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 100°C	I_{RM}	0.1 20								mA
Typical Junction Capacitance (Note 2)	C_j	350		280		200				pF
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	60								°C/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150								°C

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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FIG.1- FORWARD CURRENT DERATING CURVE

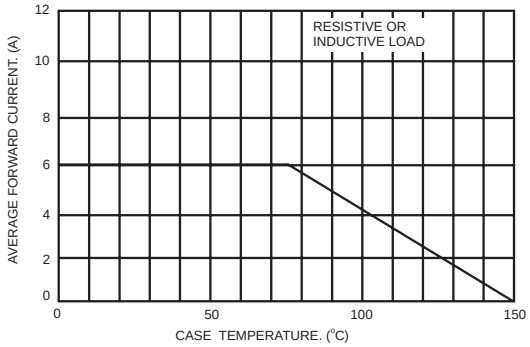

FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

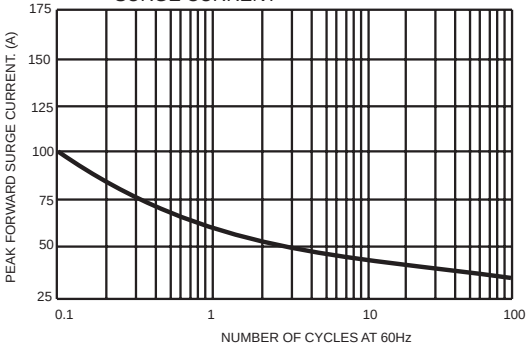

FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

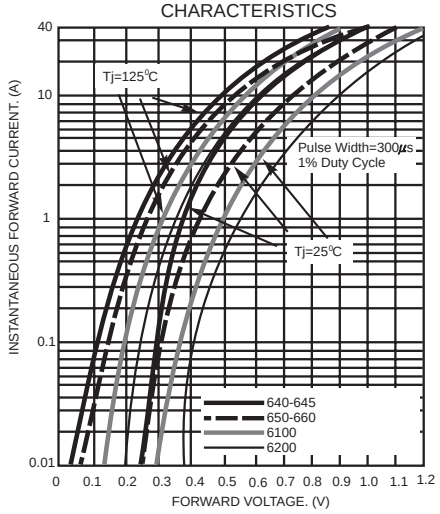

FIG.4- TYPICAL REVERSE CHARACTERISTICS

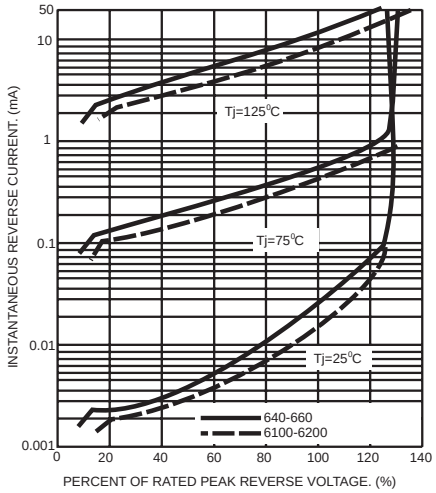

FIG.5- TYPICAL JUNCTION CAPACITANCE

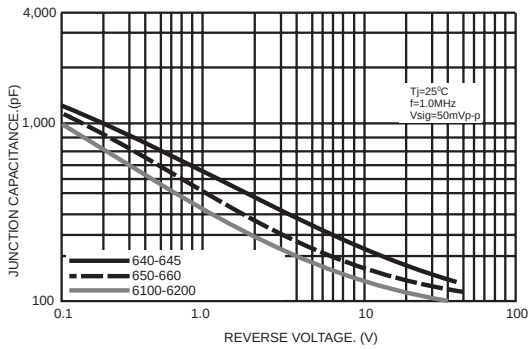

FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTIC